Ordering number: EN3824

N-Channel Silicon MOSFET



2SK1729

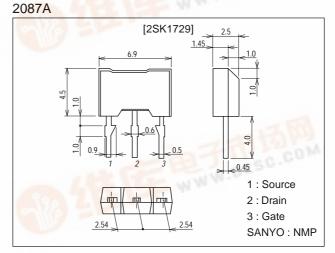
# **Ultrahigh-Speed Switching Applications**

#### **Features**

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.
- · Meets radial taping.

## **Package Dimensions**

unit:mm



## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit		
Drain-to-Source Voltage	V <sub>DSS</sub>		100	V		
Gate-to-Source Voltage	V <sub>GSS</sub>		±15	V		
Drain Current (DC)	I <sub>D</sub>		0.5	Α		
Drain Current (Pulse)	I <sub>DP</sub>	PW≤10μs, duty cycle≤1%	2	А		
Allowable Power Dissipation	PD	- A-De (1-0	1	W		
Channel Temperature	Tch	A PARTY	150	°C		
Storage Temperature	Tstg		-55 to +150	°C		

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	100			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =100V, V <sub>GS</sub> =0			100	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±12V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.0	5	2.0	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =250mA	400	700		mS
Static Drain-to-Source ON-State Resistance	R <sub>DS(on)</sub>	I <sub>D</sub> =250mA, V <sub>GS</sub> =10V		2.7	3.5	Ω
	R <sub>DS(on)</sub>	I <sub>D</sub> =250mA, V <sub>GS</sub> =4V	AL WI	3.2	4.2	Ω

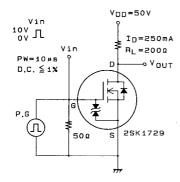
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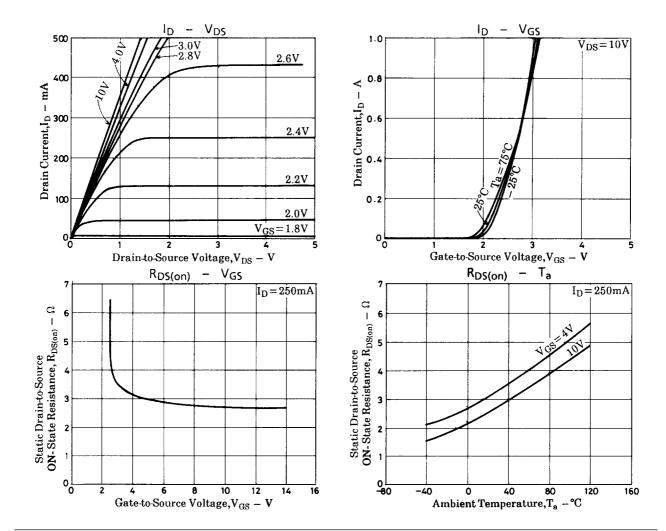
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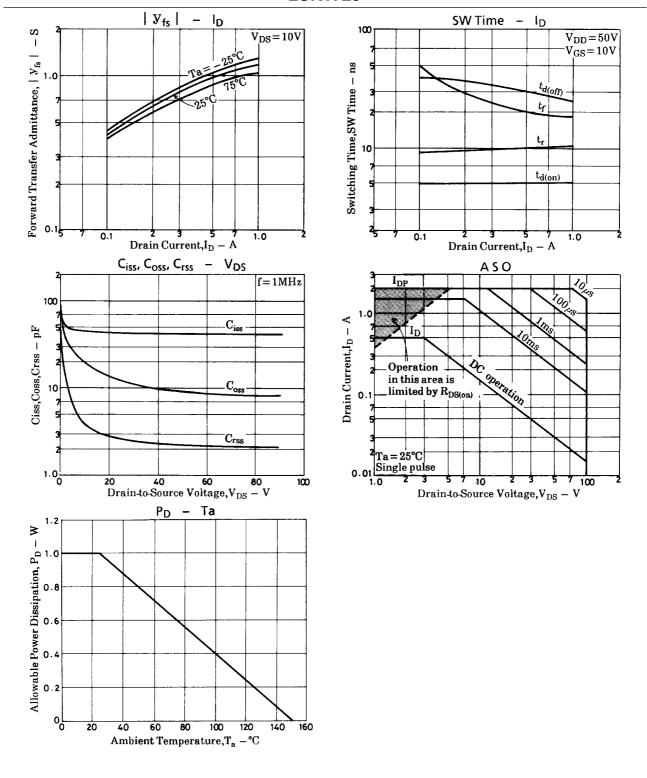
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Parameter	Symbol	Conditions	Ratings	Unit
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz	45	pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz	15	pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz	3	pF
Turn-ON Delay Time	td(on)	See specified Test Circuit	5	ns
Rise Time	t <sub>r</sub>	See specified Test Circuit	10	ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit	35	ns
Fall Time	t <sub>f</sub>	See specified Test Circuit	25	ns
Diode Forward Voltage	V <sub>SD</sub>	$I_S$ =500mA, $V_{GS}$ =0	1.0	V

### **Switching Time Test Circuit**







#### 2SK1729

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